2700 × 3 pixel CCD Linear Sensor (Color)

Description

The ILX547K is a reduction type CCD linear sensor developed for color image scanner. This sensor reads A4-size documents at a density of 300DPI. The distance between lines is only 4 line (32µm). The power supply of this device is single 5V.

Features

• Number of effective pixels: 8100 pixels

(2700 pixels × 3)

• Pixel size: $8\mu m \times 8\mu m$ ($8\mu m$ pitch)

• Distance between line: 32µm (4 lines) · Maximum data rate: $6MHz (2MHz \times 3)$

· Built-in clamp circuit

· Low lag/High sensitivity • Single 5V power supply

• Input clock pulse:

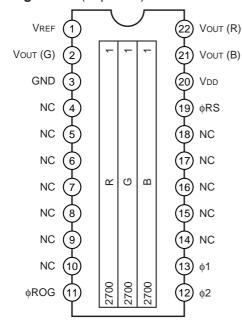
CMOS 5V drive Number of output: 3 (R, G, B)

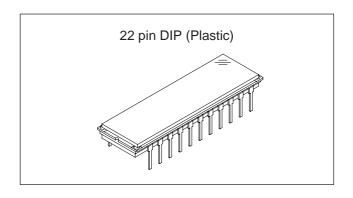
• Package: 22 pin Plastic DIP (400mil)

Absolute Maximum Ratings

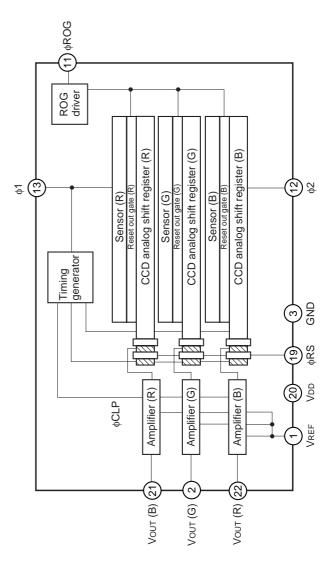
 Supply voltage V °C Operating temperature -10 to +60 Storage temperature -30 to +80°C

Pin Configuration (Top View)





Block Diagram



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Pin Description

| Pin No. | Symbol | Description | Pin No. | Symbol | Description |
|------------|----------|-------------------|------------|----------|-------------------|
| 1 | VREF | Reference voltage | 12 | ф2 | Clock pulse input |
| 2 | Vоит (G) | Signal output (G) | 13 | ф1 | Clock pulse input |
| 3 | GND | GND | 14 | NC | NC |
| 4 | NC | NC | 15 | NC | NC |
| 5 | NC | NC | 16 | NC | NC |
| 6 | NC | NC | 17 | NC | NC |
| 7 | NC | NC | 18 | NC | NC |
| 8 | NC | NC | 19 | φRS | Clock pulse input |
| 9 | NC | NC | 20 | VDD | Power supply |
| 10 | NC | NC | 21 | Vоит (B) | Signal output (B) |
| 11 | φROG | Clock pulse input | 22 | Vout (R) | Signal output (R) |

Recommended Supply Voltage

| Item | Min. | Тур. | Max. | Unit |
|------|------|------|------|------|
| VDD | 4.75 | 5 | 5.25 | V |

Input Pin Capacity

| Item | Symbol | Min. | Тур. | Max. | Unit |
|----------------------------|----------|------|------|------|------|
| Input capacity of \$1, \$2 | Сф1, Сф2 | _ | 900 | | pF |
| Input capacity of | Cors | _ | 60 | _ | pF |
| Input capacity of | Сфкоб | _ | 10 | _ | pF |

Clock Frequency

| Item | Symbol | Min. | Тур. | Max. | Unit |
|--------------------------------------------|----------------|------|------|------|------|
| Frequency of ϕ 1, ϕ 2, ϕ RS | fφ1, fφ2, fφRS | _ | 1 | 2 | MHz |

Input Clock Pulse Voltage

| Item | | Min. | Тур. | Max. | Unit |
|---------------------------------|------------|------|------|------|------|
| φ1, φ2, φRS, φROG pulse voltage | High level | 4.75 | 5.0 | 5.25 | V |
| | Low level | _ | 0 | 0.1 | V |

Electrooptical Characteristics (Note 1)

 $(Ta = 25^{\circ}C, V_{DD} = 5V, f_{\phi RS} = 1MHz, Input clock = 5Vp-p, Light source = 3200K, IR cut filter CM-500S (t = 1.0mm))$

| Item | | Symbol | Min. | Тур. | Max. | Unit | Remarks |
|---------------------------|----------------------|--------|------|------|------|------------|---------|
| | Red | RR | 3.6 | 5.6 | 7.6 | | |
| Sensitivity | Green | Rg | 4.4 | 6.8 | 9.2 | V/(lx · s) | Note 2 |
| | Blue | Rв | 3.1 | 4.8 | 6.5 | | |
| Sensitivity nonuniformity | | PRNU | _ | 4 | 20 | % | Note 3 |
| Saturation output voltage | | VSAT | 1.2 | 1.5 | _ | V | Note 4 |
| | Red | SER | 0.16 | 0.27 | _ | | Note 5 |
| Saturation exposure | Green | SEG | 0.13 | 0.22 | _ | lx·s | |
| | Blue | SEB | 0.19 | 0.31 | _ | | |
| Dark voltage average | Dark voltage average | | _ | 0.5 | 3 | mV | Note 6 |
| Dark signal nonuniformity | | DSNU | _ | 3 | 10 | mV | Note 6 |
| Image lag | | IL | | 1 | _ | % | Note 7 |
| Supply current | | Ivdd | | 9.5 | 15 | mA | _ |
| Total transfer efficiency | | TTE | 92 | 98 | _ | % | _ |
| Output impedance | | Zo | | 430 | _ | Ω | _ |
| Offset level | | Vos | _ | 3.6 | _ | V | Note 8 |

Notes)

- In accordance with the given electrooptical characteristics, the black level is defined as the average value
 of the signal level of the optical black pixels.
- 2. For the sensitivity test light is applied with a uniform intensity of illumination.
- 3. PRNU is defined as indicated below. Ray incidence conditions are the same as for Note 2.

Vout (G) = 500mV (Typ.)

$$PRNU = \frac{(V_{MAX} - V_{MIN})/2}{V_{AVE}} \times 100 [\%]$$

Where the 2700 pixels are divided to blocks of 150, R, G and B pixels, respectively. The maximum output of each block is set to VMAX, the minimum output to VMIN and the average output to VAVE.

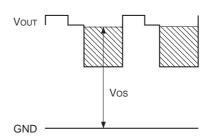
- 4. Use below the minimum value of the saturation output voltage.
- 5. Saturation exposure is defined as follows.

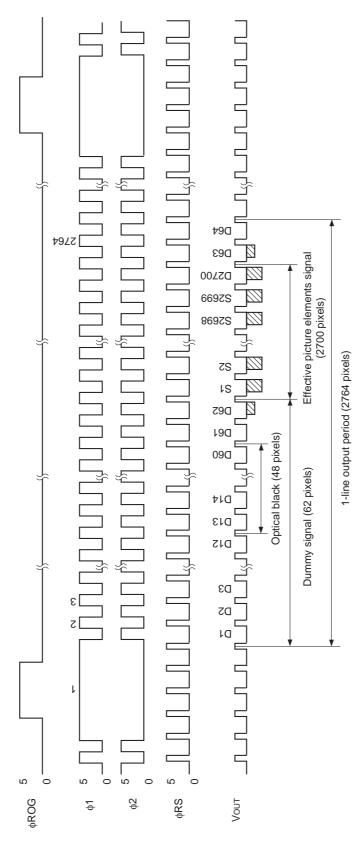
$$SE = \frac{V_{SAT}}{R}$$

Where R indicates RR, Rg, RB, and SE indicates SER, SEG, SEB.

- 6. Optical signal accumulated time τ int stands at 10ms.
- 7. Vout (G) = 500mV (Typ.)
- 8. Vos is defined as indicated bellow.

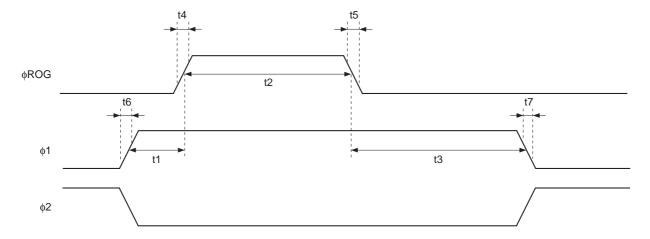
 Vour indicates Vour (R), Vour (G) and Vour (B).



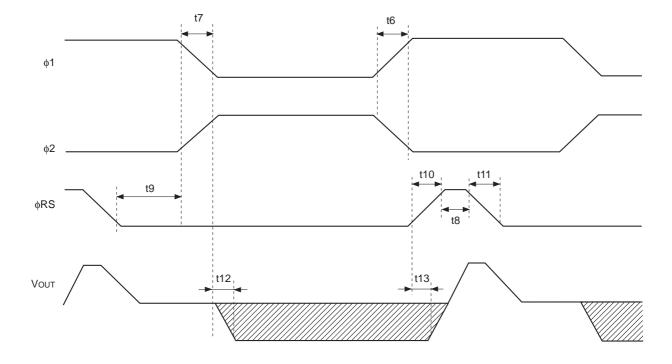


Note) The transfer pulses $(\phi 1, \phi 2)$ must have more than 2764 cycles.

Clock Timing Chart 2



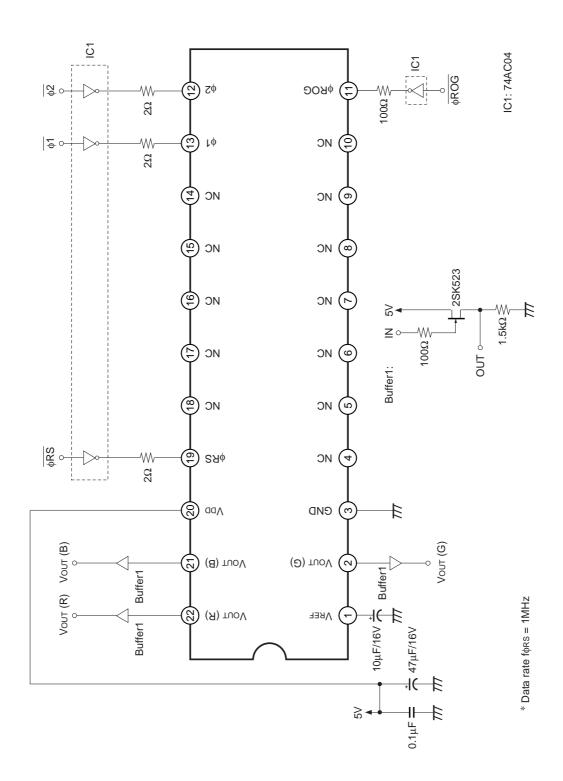
Clock Timing Chart 3



Clock Pulse Recommended Timing

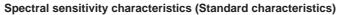
| Item | Symbol | Min. | Тур. | Max. | Unit |
|---------------------------------------|--------|------|-------|------|------|
| φROG, φ1 pulse timing | t1 | 50 | 100 | _ | ns |
| φROG pulse high level period | t2 | 800 | 1000 | _ | ns |
| φROG, φ1 pulse timing | t3 | 800 | 1000 | _ | ns |
| φROG pulse rise time | t4 | 0 | 5 | 10 | ns |
| φROG pulse fall time | t5 | 0 | 5 | 10 | ns |
| φ1 pulse rise time/φ2 pulse fall time | t6 | 0 | 10 | 60 | ns |
| φ1 pulse fall time/φ2 pulse rise time | t7 | 0 | 10 | 60 | ns |
| φRS pulse high level period | t8 | 50 | 250*1 | _ | ns |
| φRS, φ1 pulse timing | t9 | 80 | 250*1 | _ | ns |
| φRS pulse rise time | t10 | 0 | 10 | 30 | ns |
| φRS pulse fall time | t11 | 0 | 10 | 30 | ns |
| Cianal autout dalau tima | t12 | _ | 130 | _ | ns |
| Signal output delay time | t13 | _ | 40 | _ | ns |

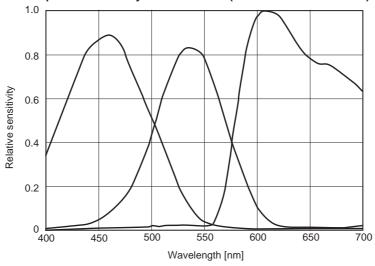
^{*1} These timing is the recommended condition under $f\varphi_{RS}=1MHz.$



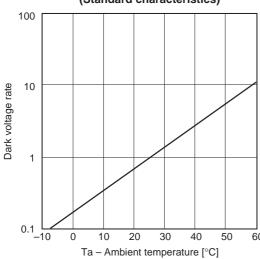
Application circuits shown are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits or for any infringement of third party patent and other right due to same.

Example of Representative Characteristics (VDD = 5V, Ta = 25°C)

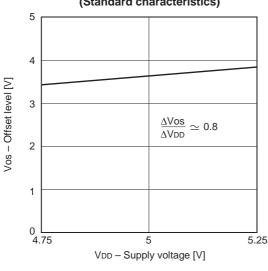




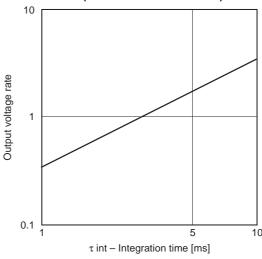
Dark voltage rate vs. Ambient temperature (Standard characteristics)



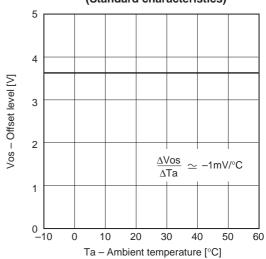
Offset level vs. Supply voltage (Standard characteristics)



Output voltage rate vs. Integration time (Standard characteristics)



Offset level vs. Ambient temperature (Standard characteristics)



Notes of Handling

1) Static charge prevention

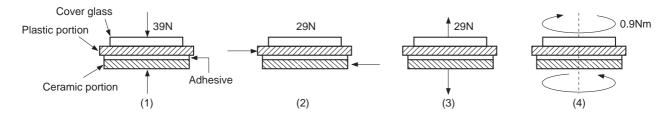
CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

- a) Either handle bare handed or use non chargeable gloves, clothes or material. Also use conductive shoes.
- b) When handling directly use an earth band.
- c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- d) Ionized air is recommended for discharge when handling CCD image sensor.
- e) For the shipment of mounted substrates, use boxes treated for prevention of static charges.

2) Notes on Handling CCD Packages

The following points should be observed when handling and installing packages.

- a) Remain within the following limits when applying static load to the package:
 - (1) Compressive strength: 39N/surface (Do not apply load more than 0.7mm inside the outer perimeter of the glass portion.)
 - (2) Shearing strength: 29N/surface(3) Tensile strength: 29N/surface
 - (4) Torsional strength: 0.9Nm



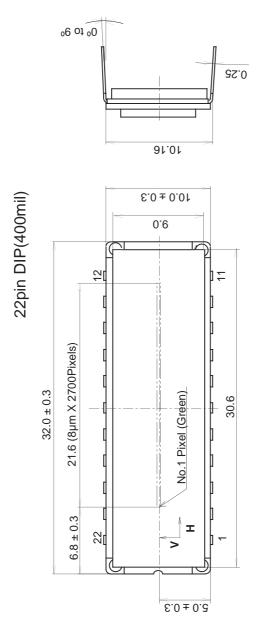
- b) In addition, if a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the ceramic portion. Therefore, for installation, either use an elastic load, such as a spring plate, or an adhesive.
- c) Be aware that any of the following can cause the package to crack or dust to be generated.
 - (1) Applying repetitive bending stress to the external leads.
 - (2) Applying heat to the external leads for an extended period of time with soldering iron.
 - (3) Rapid cooling or heating.
 - (4) Prying the plastic portion and ceramic portion away at a support point of the adhesive layer.
 - (5) Applying the metal a crash or a rub against the plastic portion.

Note that the preceding notes should also be observed when removing a component from a board after it has already been soldered.

3) Soldering

- a) Make sure the package temperature does not exceed 80°C.
- b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a grounded 30W soldering iron and solder each pin in less then 2 seconds. For repairs and remount, cool sufficiently.
- c) To dismount an imaging device, do not use a solder suction equipment. When using an electric desoldering tool, ground the controller. For the control system, use a zero cross type.

- 4) Dust and dirt protection
 - a) Operate in clean environments.
 - b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
 - c) Clean with a cotton bud and ethyl alcohol if the glass surface is grease stained. Be careful not to scratch the glass.
 - d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- 5) Exposure to high temperatures or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.
- 6) CCD image sensors are precise optical equipment that should not be subject to mechanical shocks.



The thickness of the cover glass is 0.7mm, and the refractive index is 1.5. The height from the bottom to the sensor surface is 1.61 \pm 0.3mm. ζ. (d) 0.3 2.80 ± 08.5 01.2 0.51 2.54

d.0 ± 0.4

PACKAGE STRIICTIIRE

| PACKAGE MATERIAL | Plastic , Ceramic |
|------------------|-------------------|
| LEAD TREATMENT | GOLD PLATING |
| LEAD MATERIAL | 42 ALLOY |
| PACKAGE MASS | 2.21g |
| DRAWING NUMBER | LS-D8-01(E) |

| JIVE | Plastic , Cer |
|--------------------|------------------|
| LACKAGE STINGSTONE | PACKAGE MATERIAL |